



### **60V N-Channel Enhancement Mode MOSFET**

Voltage

60 V

Current

40 A

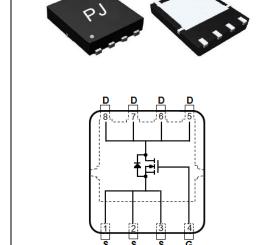
#### **Features**

- $R_{DS(ON)}$ ,  $V_{GS}@10V$ , $I_D@15A<21m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ , $I_{D}@8A$ < $24m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

- Case: DFN5060-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0028 ounces, 0.08 grams
- Marking: Q5466A

## DFN5060-8L



## $\textbf{Maximum Ratings and Thermal Characteristics} \; (T_A = 25 ^{\circ} C \; \text{unless otherwise noted})$

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	60	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	T <sub>C</sub> =25°C	l <sub>D</sub>	40	A	
	T <sub>C</sub> =100°C		25		
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	160		
Power Dissipation	T <sub>C</sub> =25°C	Po	83	W	
	T <sub>C</sub> =100°C		33		
Continuous Drain Current	T <sub>A</sub> =25°C	Ι <sub>D</sub>	6.5	Α	
	T <sub>A</sub> =70°C		5	Α	
Power Dissipation	T <sub>A</sub> =25°C	D-	2.0	W	
Power Dissipation	T <sub>A</sub> =70°C	Pb	1.3		
Single Pulse Avalanche Energy (Note 6)		E <sub>AS</sub>	42	mJ	
Operating Junction and Storage Temperature Range		$T_{J}$ , $T_{STG}$	-55~150	°C	
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Case	$R_{ heta JC}$	1.5	°C/W	
	Junction to Ambient	$R_{ heta JA}$	62.5		

• Limited only By Maximum Junction Temperature





### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =250uA	60	1	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250$ uA	1.0	1.73	2.5	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V,I <sub>D</sub> =15A	-	18	21	mΩ
		V <sub>GS</sub> =4.5V,I <sub>D</sub> =8A	-	21	24	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =60V, $V_{GS}$ =0V	-	-	1.0	uA
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)			_			
Total Gate Charge	$Q_g$	V <sub>DS</sub> =30V, I <sub>D</sub> =15A, V <sub>GS</sub> =10V <sup>(Note 1,2)</sup>	-	28	-	nC
Gate-Source Charge	$Q_gs$		-	3.5	-	
Gate-Drain Charge	$Q_{gd}$		-	6.5	-	
Input Capacitance	Ciss	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V, f=1.0MHZ	-	1680	-	pF
Output Capacitance	Coss		-	115	-	
Reverse Transfer Capacitance	Crss	I=1.0IVII IZ	-	85	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	7.2	-	
Turn-On Rise Time	t <sub>r</sub>	$V_{DD}$ =30V, $I_{D}$ =1A, $V_{GS}$ =10V, $R_{G}$ =6 $\Omega$ (Note 1,2)	-	38	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	34	-	
Turn-Off Fall Time	t <sub>f</sub>		-	8.2	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	ı				40	_
Diode Forward Current	I <sub>S</sub>			-	40	Α
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A,V <sub>GS</sub> =0V	-	0.7	1.0	V

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited.
- 5. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH,  $I_{AS}$ =29A,  $V_{DD}$ =25V,  $V_{GS}$ =10V
- 7. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

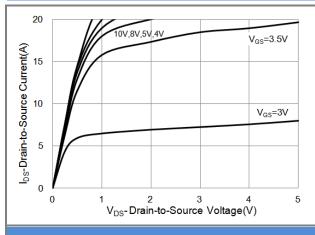


Fig.1 Output Characteristics

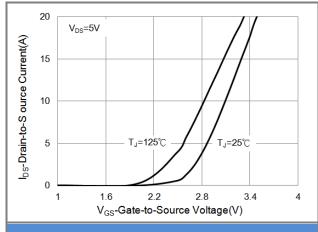


Fig.2 Transfer Characteristics

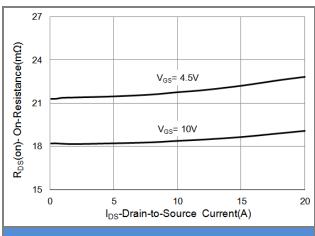


Fig.3 On-Resistance vs. Drain Current

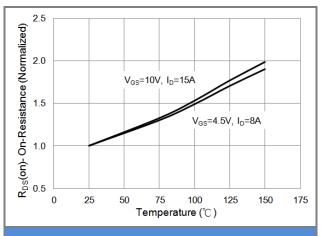
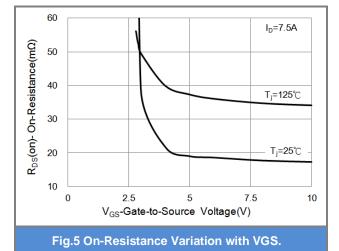


Fig.4 On-Resistance vs. Junction temperature

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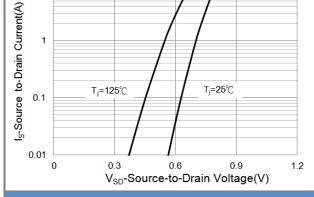


Fig.6 Source-Drain Diode Forward Voltage





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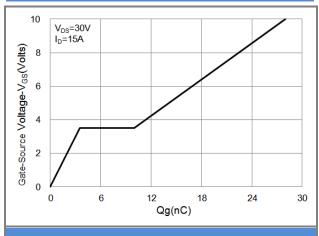


Fig.7 Gate-Charge Characteristics

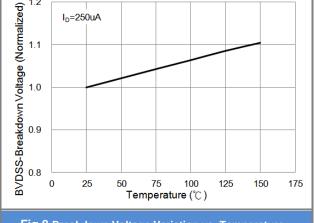


Fig.8 Breakdown Voltage Variation vs. Temperature

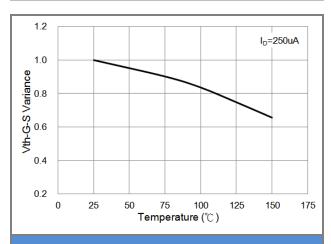


Fig.9 Threshold Voltage Variation with Temperature

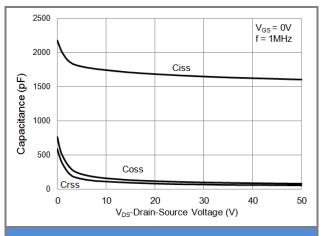


Fig.10 Capacitance vs. Drain-Source Voltage

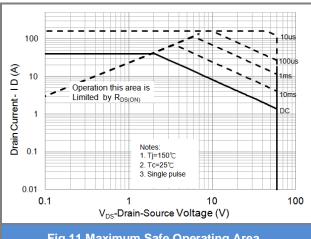


Fig.11 Maximum Safe Operating Area





#### **TYPICAL CHARACTERISTIC CURVES**

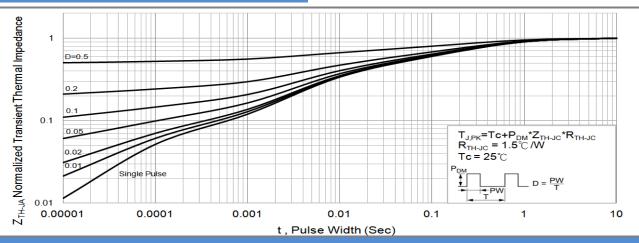


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

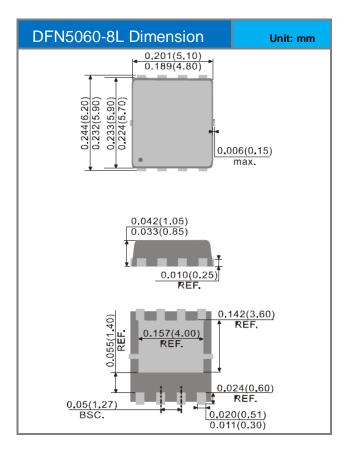


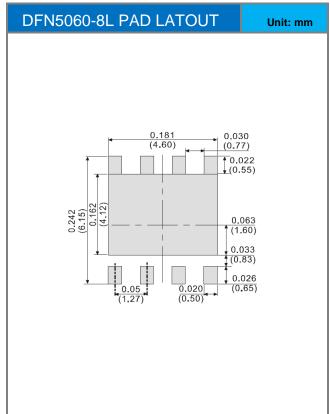


#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJQ5466A_R2_00001	DFN5060-8L	3000pcs / 13" reel	Q5466A	Halogen free

### **Packaging Information & Mounting Pad Layout**









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